


**RoHS  
COMPLIANCE**
**HALOGEN  
FREE**


## **SS13M/SS14M/SS16M**

**1.0Amp Surface Mount Schottky Barrier Rectifier  
Micro SMA**

### **Features**

- ◊ Very low profile - typical height of 0.68mm
- ◊ Ideal for automated placement
- ◊ Low forward voltage drop. Low power loss.
- ◊ High efficiency
- ◊ Meet MSL level 1, per J-STD-020D, lead free maximum peak of 260 °C
- ◊ Solder dip 265 °C max. 10 s, per JESD 22-A111
- ◊ Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- ◊ Halogen-free according to IEC 61249-2-21 definition

### **Typical Application**

- ◊ For use in low voltage high frequency inverter, freewheeling, DC to DC converter, and polarity protection applications.

### **Mechanical Data**

- ◊ Case: Micro SMA
- ◊ Molding Compound meet UL 94V-0 flammability rating.
- ◊ Terminals: Matte tin plated leads, solderable per J-STD-002B, and JESD22-B102D.
- ◊ Polarity: Indicated by Cathode Band
- ◊ Packaging: 8 mm tape per EIA Std RS-481
- ◊ Weight: 0.006 gram

### **Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified.

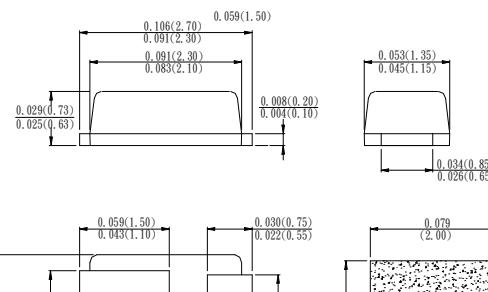
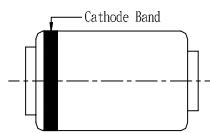
Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbol	SS13M	SS14M	SS16M	Unit	
Device Marking Code		A	B	C		
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	30	40	60	V	
Maximum Average Forward Rectified Current (Fig.1)	I <sub>(AV)</sub>			1	A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load	I <sub>FSM</sub>			25	A	
Maximum Instantaneous Forward Voltage @ 0.5A / T <sub>a</sub> =25°C @ 0.5A / T <sub>a</sub> =125°C @ 1.0A / T <sub>a</sub> =25°C @ 1.0A / T <sub>a</sub> =125°C	V <sub>F</sub>	TYP. 0.45 0.35 0.52 0.46	MAX. - - 0.55 0.50	TYP. 0.51 0.46 0.64 0.57	MAX. - - 0.68 0.60	V
Maximum Reverse Current @ Rated VR T <sub>a</sub> =25 °C T <sub>a</sub> =125 °C T <sub>a</sub> =150 °C	I <sub>R</sub>	TYP. 1 2 6	MAX. 50 10 -	TYP. 2 2 7	MAX. 50 10 -	uA mA mA
Typical Junction Capacitance ( Note 1)	C <sub>j</sub>	50		40	pF	
Typical Thermal Resistance (Note 2)	R <sub>θJA</sub> R <sub>θJL</sub> R <sub>θJC</sub>		125 30 40		°C/W	
Operating Temperature Range	T <sub>J</sub>		-55 to + 150		°C	
Storage Temperature Range	T <sub>STG</sub>		-55 to + 150		°C	

Note1: Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

Note2: Mount on Cu-Pad Size 6mm x 6mm x 1.6mm on P.C.B.



**Suggested Mounting Pad Layout**

### **Dimensions in inches and (millimeters)**

Marking Diagram



X = Device Marking Code

Y = Year

M = Month

## RATINGS AND CHARACTERISTIC CURVES (SS13M/SS14M/SS16M)

Fig.1 Maximum Forward Current Derating Curve

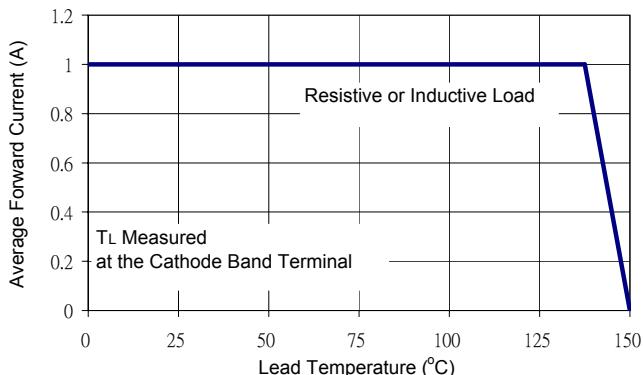


Fig. 2 Maximum Forward Surge Current

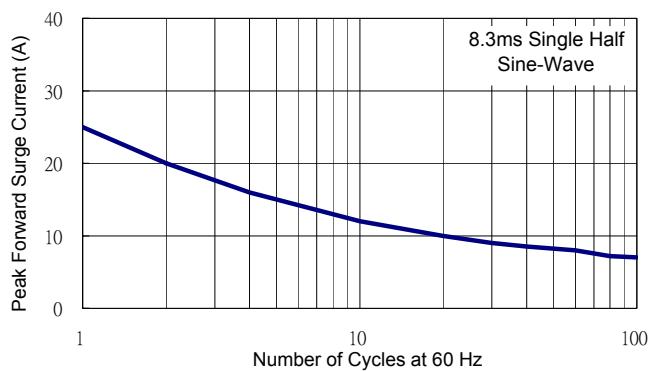


Fig. 3 Typical Forward Characteristics - SS13M/14M

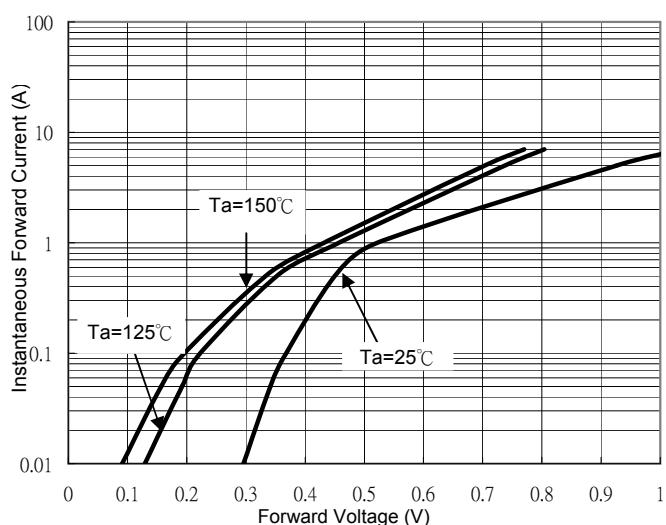


Fig. 4 Typical Forward Characteristics - SS16M

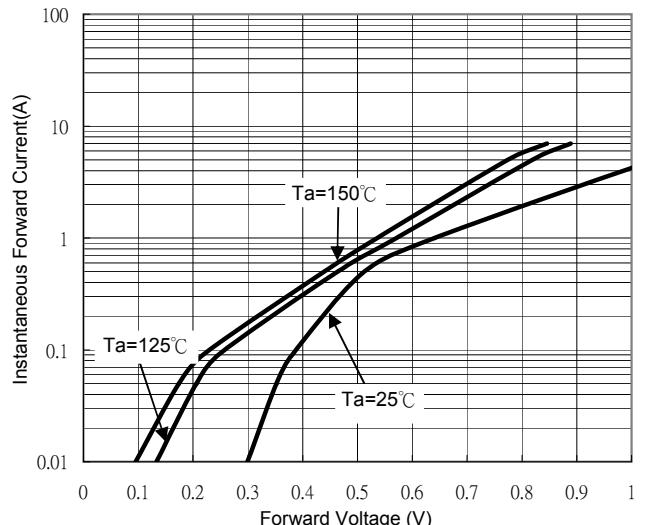


Fig. 5 Typical Reverse Characteristics - SS13M/14M

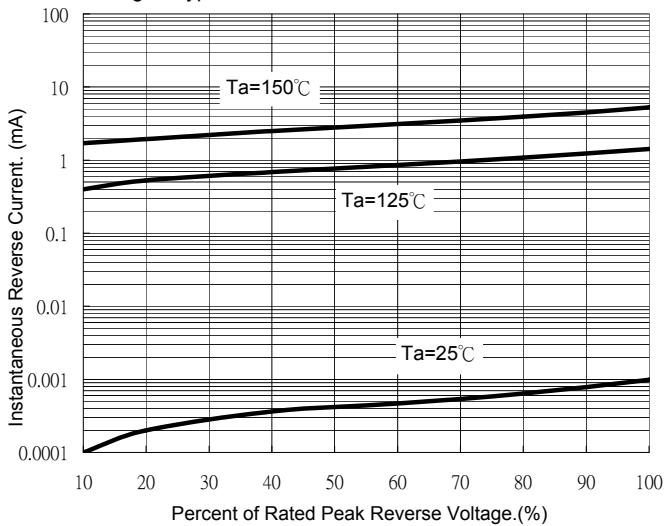
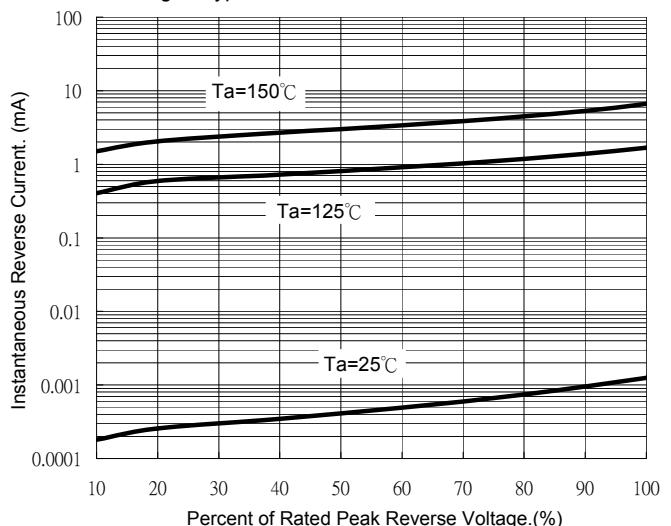


Fig. 6 Typical Reverse Characteristics - SS16M



## RATINGS AND CHARACTERISTIC CURVES (SS13M/SS14M/SS16M)

Fig. 7 Typical Junction Capacitance

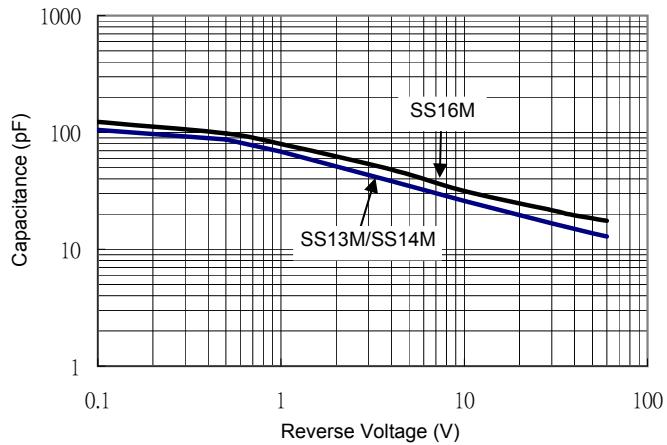


Fig. 8 Typical Transient Thermal Impedance

